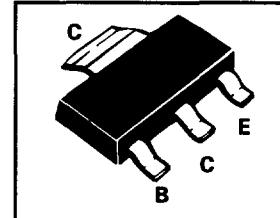


SOT223 NPN SILICON PLANAR MEDIUM POWER TRANSISTOR

ISSUE 3 - NOVEMBER 1995

FZT489

COMPLEMENTARY TYPE – FZT589
PARTMARKING DETAIL – FZT489



ABSOLUTE MAXIMUM RATINGS.

| PARAMETER | SYMBOL | VALUE | UNIT |
|---|----------------|-------------|------|
| Collector-Base Voltage | V_{CBO} | 50 | V |
| Collector-Emitter Voltage | V_{CEO} | 30 | V |
| Emitter-Base Voltage | V_{EBO} | 5 | V |
| Continuous Collector Current | I_C | 1 | A |
| Peak Pulse Current | I_{CM} | 4 | A |
| Base Current | I_B | 200 | mA |
| Power Dissipation at $T_{amb}=25^\circ\text{C}$ | P_{tot} | 2 | W |
| Operating and Storage Temperature Range | $T_j; T_{stg}$ | -55 to +150 | °C |

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^\circ\text{C}$).

| PARAMETER | SYMBOL | MIN. | MAX. | UNIT | CONDITIONS. |
|---------------------------------------|-----------------------|------|------|------|---|
| Breakdown Voltages | $V_{(BR)CBO}$ | 50 | | V | $I_C=100\mu\text{A}$ |
| | $V_{CEO(\text{sus})}$ | 30 | | V | $I_C=10\text{mA}^*$ |
| | $V_{(BR)EBO}$ | 5 | | V | $I_E=100\mu\text{A}$ |
| Collector Cut-Off Current | I_{CBO} | | 100 | nA | $V_{CE}=30\text{V}$ |
| | I_{CES} | | 100 | nA | $V_{CES}=30\text{V}$ |
| Emitter Cut-Off Current | I_{EBO} | | 100 | nA | $V_{EB}=4\text{V}$ |
| Collector-Emitter Saturation Voltage | $V_{CE(\text{sat})}$ | | 0.3 | V | $I_C=1\text{A}, I_B=100\text{mA}^*$ |
| | | | 0.6 | V | $I_C=2\text{A}, I_B=200\text{mA}^*$ |
| Base-Emitter Saturation Voltage | $V_{BE(\text{sat})}$ | | 1.1 | V | $I_C=1\text{A}, I_B=100\text{mA}^*$ |
| Base-Emitter Turn On Voltage | $V_{BE(\text{on})}$ | | 1.0 | V | $I_C=1\text{A}, V_{CE}=2\text{V}^*$ |
| Static Forward Current Transfer Ratio | h_{FE} | 100 | 300 | | $I_C=1\text{mA}, V_{CE}=2\text{V}^*$ |
| | | 100 | | | $I_C=1\text{A}, V_{CE}=2\text{V}^*$ |
| | | 60 | | | $I_C=2\text{A}, V_{CE}=2\text{V}^*$ |
| | | 20 | | | $I_C=4\text{A}, V_{CE}=2\text{V}^*$ |
| Transition Frequency | f_T | 150 | | MHz | $I_C=50\text{mA}, V_{CE}=10\text{V}$ $f=100\text{MHz}$ |
| Collector-Base Breakdown Voltage | V_{CBO} | | 10 | pF | $V_{CE}=10\text{V}, f=1\text{MHz}$ |

*Measured under pulsed conditions. Pulse width=300μs. Duty cycle ≤ 2%
For typical characteristics graphs see FMMT449 datasheet